

10A SBR[®] SUPER BARRIER RECTIFIER

Product Summary

| V _{RRM} (V) | lo (A) | V _{F MAX} (V) @+25°C | I _{R MAX} (mA) @+25°C |
|----------------------|--------|-------------------------------|--------------------------------|
| 45 | 10 | 0.58 | 0.3 |

Description and Applications

This Super Barrier Rectifier (SBR) diode has been designed to meet the stringent requirements of Automotive Applications. It is ideally suited to use as:

- · Polarity Protection Diode
- Re-circulating Diode
- Switching Diode

Features

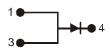
- 100% Avalanche Tested.
- Patented SBR technology provides a superior avalanche capability than schottky diodes ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop (VF); better efficiency and cooler operation.
- Reduced high temperature reverse leakage; increased reliability against thermal runaway failure at high temperature
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 63
- Weight: 0.33 grams (approximate)



Top View



Polarity

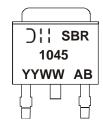
Ordering Information (Note 4)

| Part Number | Compliance | Case | Packaging |
|---------------|------------|--------------|------------------|
| SBR1045D1Q-13 | Automotive | TO252 (DPAK) | 2500/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



SBR1045 = Product Type Marking Code AB = Foundry and Assembly Code YYWW = Date Code Marking YY = Last two digits of year (ex: 13 = 2013) WW = Week (01 - 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

| Characteristic | Symbol | Value | Unit |
|---|---|-------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm V _{rwm} V _{rm} | 45 | V |
| RMS Reverse Voltage | V _{R(RMS)} | 32 | V |
| Average Rectified Output Current | I ₀ | 10 | Α |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load | I _{FSM} | 90 | Α |
| Repetitive Peak Avalanche Power (1µs, +25°C) | P _{ARM} | 5000 | W |
| Non-Repetitive Avalanche Energy (T _J = +25°C, I _{AS} = 12A, L = 10mH) | E _{AS} | 200 | mJ |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|-------------|-------------|------|
| Typical Thermal Resistance | | | |
| Thermal Resistance Junction to Ambient (Note 5) | Reja | 29 | °C/W |
| Thermal Resistance Junction to Case (Note 5) | Rejc | 3 | C/VV |
| Operating and Storage Temperature Range | T_J,T_STG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|------------------------------------|----------------|-----|------|------|------|---------------------------------|
| Reverse Breakdown Voltage (Note 6) | $V_{(BR)R}$ | 45 | - | - | V | $I_R = 0.5 \text{mA}$ |
| | V _F | _ | 0.42 | _ | V | $I_F = 5A, T_J = +25$ °C |
| Forward Voltage Drop | | _ | 0.37 | - | | $I_F = 5A, T_J = +125$ °C |
| Forward Voltage Drop | | _ | 0.53 | 0.58 | | $I_F = 10A, T_J = +25^{\circ}C$ |
| | | _ | 0.50 | _ | | $I_F = 10A, T_J = +125$ °C |
| Leakage Current (Note 6) | I _R | _ | 150 | 300 | μA | $V_R = 45V, T_J = +25^{\circ}C$ |
| Leakage Current (Note 8) | | = | 50 | _ | mA | $V_R = 45V, T_J = +125$ °C |
| Total Capacitance | C _T | - | 400 | - | pF | $V_R = 5V$, $f = 1MHz$ |
| Total Capacitance | | | | | | $T_J = +25^{\circ}C$ |

Notes:

- Device mounted on polymide substrate, 240mm² Copper pad, double-sided PC Board.
 Short duration pulse test used to minimize self-heating effect.

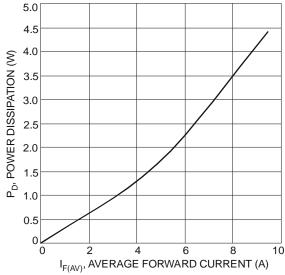


Fig. 1 Forward Power Dissipation Notes:7. Polymide, 2oz. Copper 16x minimum recommended pad layout per http://www.diodes.com

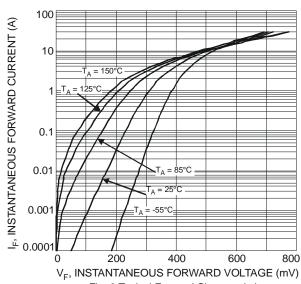
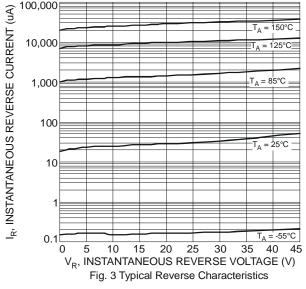
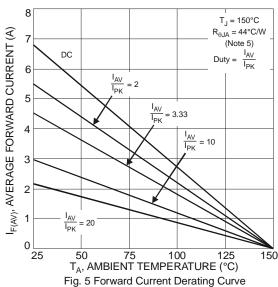
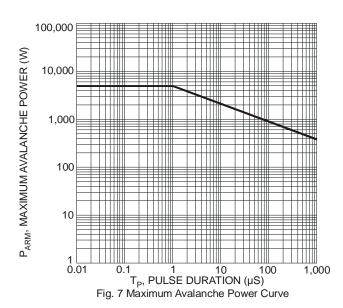


Fig. 2 Typical Forward Characteristics









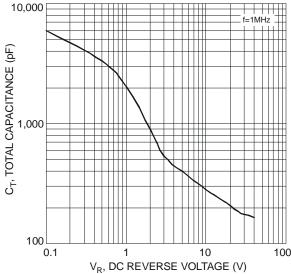


Fig. 4 Total Capacitance vs. Reverse Voltage

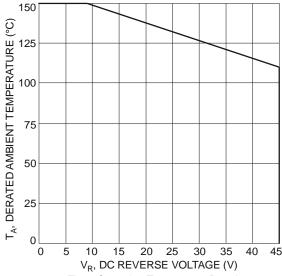
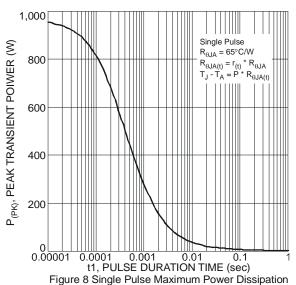
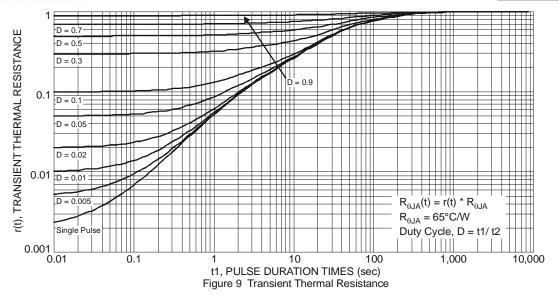


Fig. 6 Operating Temperature Derating

Notes:8. Polymide, 2oz. Copper 16x minimum recommended pad layout per http://www.diodes.com

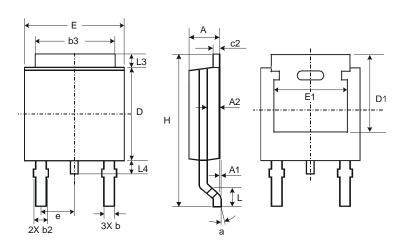






Package Outline Dimensions

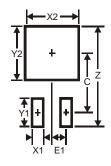
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| TO252 | | | | | |
|-------|----------------------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 2.19 | 2.39 | 2.29 | | |
| A1 | 0.00 | 0.13 | 0.08 | | |
| A2 | 0.97 | 1.17 | 1.07 | | |
| b | 0.64 | 0.88 | 0.783 | | |
| b2 | 0.76 | 1.14 | 0.95 | | |
| b3 | 5.21 | 5.46 | 5.33 | | |
| c2 | 0.45 | 0.58 | 0.531 | | |
| D | 6.00 | 6.20 | 6.10 | | |
| D1 | 5.21 | _ | _ | | |
| е | _ | _ | 2.286 | | |
| Ε | 6.45 | 6.70 | 6.58 | | |
| E1 | 4.32 | _ | _ | | |
| Н | 9.40 | 10.41 | 9.91 | | |
| L | 1.40 | 1.78 | 1.59 | | |
| L3 | 0.88 | 1.27 | 1.08 | | |
| L4 | 0.64 | 1.02 | 0.83 | | |
| а | 0° | 10° | _ | | |
| All | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | |
|------------|---------------|--|
| Z | 11.6 | |
| X1 | 1.5 | |
| X2 | 7.0 | |
| Y1 | 2.5 | |
| Y2 | 7.0 | |
| С | 6.9 | |
| E1 | 2.3 | |



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